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TERNARY PHASE EQUILIBRIA IN TRANSITION METAL-BORON-CARBON-SILICON SYSTEMS

PART I. BINARY SYSTEMS Volume XIV. Constitution of the Hafnium-Vanadium and Hafnium-Chromium Systems

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Aerojet-General Corporation

TECHNICAL REPORT AFML-TR-65-2, PART I, VOLUME XIV

MAY 1968

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FOREWORD

The research described in this report was carried out at the Materials Research Laboratory, Aerojet-General Corporation, Sacramento, California, under USAF Contract No. AF 33(615)-1249. The contract was initiated under Project No. 7350, Task No. 735001, and was administered under the direction of the Air Force Materials Laboratory, with Lt. P.J. Marchiando acting as Project Engineer, and Dr. E. Rudy, Aerojet-General Corporation, as Principal Investigator. Professor Dr. Hans Nowotny, University of Vienna, served as consultant to the project.

The project, which includes the experimental and theoretical investigations of ternary and related binary systems in the system classes $Me_1 - Me_2 - C$, $Me_1 - Me_2 - B$, $Me_1 - Si - B$ and $Me_1 - Si - C$, was initiated on 1 January 1964. An extension effort to this contract commenced in January 1966.

The phase diagram work on the binary systems described in this report were carried out by E. Rudy and St. Windisch. Assisting in the investigations were: J. Hoffman (Metallographic preparations), J. Pomodoro (sample preparation), and R. Cobb (X-ray exposures and photographic work). C.E. Brukl assisted in some of the lattice parameter measurements.

Chemical analysis of the alloys was performed under the supervision of Mr. W.E. Trahan, Quality Control Division of Aerojet-General Corporation. The authors wish to thank Mr. R. Cristoni for the preparation of the illustrations, and Mrs. J. Weidner, who typed the report.

The manuscript of this report was released by the authors November 1967 for publication.

Other reports issued under USAF Contract AF 33(615)-1249 have included:

Part I. Related Binaries

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Volume I.	Mo-C System
Volume II.	Ti-C and Zr-C Systems
Volume III.	Systems Mo-B and W. P
Volume IV.	Hf-C System
Volume V.	Ta-C System. Partial Investigations in
Volume VI.	W-C System. Supplemental Information on the Mo-C System
Volume VII.	Ti-B System
Volume VIII.	Zr-B System
Volume IX.	Hf-B System
Volume X.	V-B. Nh-B and To B Guete
Volume XI	Final Report on the March
Volume XII.	Revision of the Vanadium-Carbon and Niobium-
Volume XIII.	The Systems Zr-Si and Hf-Si

FOR EWORD (cont'd)

Part II. Ternary Systems

Volume I.	Ta-Hf-C System			
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Volume IV.	Ti-Zr-C, Ti-Hf-C, and Zr-Hf-C Sustant			
Volume V.	Ti-Hf-B System			
Volume VI.	Zr-Hf-B System			
Volume VII.	Systems Ti-Si-C. Nb-Si-C. and W-Si-C			
Volume VIII.	Ta-W-C System			
Volume IX.	Zr-W-B System, Pseudo-Binary System TaB,-HfB,			
Volume X.	Systems Zr-Si-C, Hf-Si-C, Zr-Si-B, and Hf-Si-B			
Volume XI.	Systems Hf-Mo-B and Hf-W-B			
Volume XII.	Ti-Zr-B System			
Volume XIII.	Phase Diagrams of the Systems Ti-B-C, Zr-B-C, and Hf-B-C			
Volume XIV.	The Hafnium-Iridium-Boron System			
Volume XV.	Constitution of Niobium-Molybdenum-Carbon Alloys			
Volume XVI.	The Vanadium-Niobium-Carbon System			
Volume XVII.	Constitution of Ternary Ta-Mo-C Allove			

Part III. Special Experimental Techniques

Volume I. Volume II.	High Temperature Differential Thermal Analysis A Pirani-Furnace for the Precision Determina- tion of the Melting Temperatures of Refractory Metallic Substances

Part IV. Thermochemical Calculations

Volume I.	Thermodynamic Properties of Group IV. V. and
Volume II.	VI Binary Transition Metal Carbides. Thermodynamic Interpretation of Ternary Phase Diagrams
Volume III.	Computational Approaches to the Calculation of Ternary Phase Diagrams.

This technical report has been reviewed and is approved.

W. G. RAMKE Chief, Ceramics and Graphite Branch Metals and Ceramics Division Air Force Materials Laboratory

ABSTRACT

The binary systems hafnium-vanadium and hafnium-chromium were investigated by means of X-ray, melting point, DTA, and metallographic techniques. Phase diagrams of both systems from approximately 1100°C through the melting range were established.

In the hafnium-vanadium system, the vanadium-stabilized β -Hf solid solution decomposes in a rapid eutectoid reaction at 1190 + 25°C and 19 At% V into the a-modification and HfV₂. The maximum vanadium exchange in β -Hf is 23.5 At% at 1456°C, whereas the solid solubility in a-hafnium is less than 2 At%. Vanadium dissolves up to ~4 At% hafnium.

The only intermediate compound, HfV_2 , has a fcc cubic, C15 type structure, with a = 7.398 Å at the hafnium-rich, and a = 7.386 Å at the vanadiumrich homogeneity limit. The phase melts congruently at 1550 + 10°C at the stoichiometric composition.

Eutectic equilibria are formed between HfV₂ and β -Hf at 43 At% V and 1456 °C, and between HfV₂ and V at 69 At% V and 1520 °C.

The hafnium-chromium system contains one intermediate phase, HfCr₂, with a hexagonal, Cl4-type of structure. The phase, which extends from approximately 64 At% Cr (a = 5.090 Å; c = 8.25 Å), to \sim 67 At% Cr (a = 5.056 Å; c = 8.21 Å) at 1500°C, melts congruently at 1870 + 15° at the stoichiometric composition.

Beta-hafnium takes a maximum of 13 At% Cr into solid solution (1170°C), and the β -solid solution containing 11.5 At% Cr decomposes in a rapid eutectoid reaction at 1355 + 15° into a-hafnium and HfCr₂. The maximum solubilities in a-Hf and in Cr are less than 2 At%.

Eutectic equilibria are formed between the β -Hf phase and HfCr, at 41 At% Cr and 1510 + 8°, and between HfCr₂ and Cr at 87 At% Cr and 1690 + 15°C.

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I. INTRODUCTION AND SUMMARY OF PREVIOUS WORK

In the course of our work on ternary systems of refractory transition metals with carbon, boron, and silicon⁽¹⁾, it also was necessary to examine or redetermine the phase relationships in some of the metal boundary systems⁽²⁾.

A tentative diagram for the hafnium-vanadium system was published by Komjathy⁽³⁾. According to this work, the only intermediate phase, HfV_2 , melts congruently at temperatures above 2000°C. Eutectic equilibria are formed between HfV_2 and V at 1600°C, and between HfV_2 and Hf at 1550 \pm 15° and 53 to 72 At% Hf. The solid solubility of hafnium in vanadium at 1500°C was said to lie between 7 and 8 wt% (2.1 to 2.4 At%).

Using high purity ingredients, the entire system was reinvestigated recently by Deardorff et al.⁽⁴⁾. According to the latter authors, HfV_2 forms peritectically from melt and vanadium at 1480°C. The maximum solubility of vanadium in β -hafnium amounts to ~8 wt% (23 At%) and the vanadium-stabilized β -Hf solid solution was shown to decompose eutectoidally at 1165°C and 6 wt% (18 At%) vanadium into the a-modification and HfV_2 . A eutectic equilibrium between β -Hf and HfV_2 was placed at 20 wt% (47 At%) vanadium and 1395°C. Vanadium dissolved approximately 11 wt% (3.5 At%)hafnium, at 1480°C with the solubility rapidly decreasing as the temperature is lowered.

The phase HfV₂ has a fcc-cubic, C15 type of structure⁽⁵⁾, with $a = 7.386 \text{ A}^{(5)}$. Other measurements included $a = 7.38 \text{ A}^{(4)}$, and $a = 7.400 \text{ A}^{(6)}$.

The only information available on the hafnium-chromium systems concerns the structure of the intermediate phase $HfCr_2$: $Elliott^{(7)}$, in his investigation of Laves type intermediate phases, first assigned a hexagonal, C36 (MgNi₂) type of structure with a = 5.057 Å and c = 16.358 Å, but did not rule out the possibility of a transformation to the C14 (MgZn₂) type at lower temperatures. In a reinvestigation of the compound by the same author⁽⁶⁾, HfCr₂ was shown to be dimorphic, having the C14-type structure, with a = 5.067 Å and c = 8.237 Å up to 1000°C. At 1200°C, the cubic C15 type with a = 7.15 Å appeared. The MgZn₂-type structure was confirmed by Alisova et al.⁽⁸⁾, but

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was attributed to the high temperature polymorph; the C15-type (a = 7.260 Å) was said to be stable below 1100°C.

II. EXPERIMENTAL

A. STARTING MATERIALS AND ALLOY PREPARATION

The powdered elements were used in the preparation of the experimental alloys.

Hafnium metal powder (Wah Chang Corp., Albany, Oregon) was available in two grades, of which one contained 1.35 wt% (2.6 At%) Zr, whereas the other was essentially zirconium-free (175 ppm). Samples were prepared from both materials. The results were identical and hence no distinction of the specimens prepared from the two different grades will be necessary.

The chemical analysis of both powders were as follows (in ppm, values in brackets refer to the low zirconium grade): A1-60 (39); C-60 (360); Nb-<100 (200), Fe-120 (165), H-not dt. (160); Fe-120 (165); Mg-250 (10); N-100 (485); O-1100 (980); Si-<40 (150); Ta-<200 (<200); sum of other metallic impurities-<200 (<200). The lattice parameters measured for both materials were a = 3.195 Å and c = 5.051 Å.

High purity chromium powder (>99.9%) was obtained from H.C. Starck Corporation, Berlin, Germany. The main impurities included, in ppm: Fe, \sim 200; Mg, \sim 100, and O + N, 250.

The vanadium powder, as purchased, had an overall purity of better than 99.65%. The supplier was Oregon Metallurgical Corporation, Albany, Oregon. The major impurities included oxygen (810 ppm) nitrogen (140 ppm), and iron (450 ppm). The vanadium had a lattice parameter of a = 3.026 Å.

After cold compaction of the well-mixed powders, the specimens from both systems were prehomogenized under vacuum (<2 x 10^{-6} Torr) for 2 hrs at 1250°C in a tungsten-mesh element furnace. For added protection

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of the samples, the top of the tantalum sample container was filled with zirconium sponge to act as getter for rest gases contained in the furnace.

After the melting experiments in the Pirani-furnace, the specimens were cut into several pieces and used for studies of the solid state sections of the systems. Homogenization treatments for hafnium-vanadium alloys were 4 hrs at 1300°C, 6 hrs at 1150°C, and 220 hrs at 900°C. The hafniumchromium alloys received, after melting, heat treatments at 1400°C (1 hr), 1200°C (7 hrs) and,900°C (220 hrs).

A selected number of specimens, mostly for metallographic purposes and for DTA-studies, were arc melted under high purity helium in a nonconsumable electrode arc furnace.

B. DETERMINATION OF MELTING TEMPERATURES AND DIFFERENTIAL THERMAL ANALYSIS

The melting temperatures of the alloys were determined using the method devised by Pirani and Alterthum⁽⁹⁾. Details of the apparatus used in this laboratory as well as temperature calibration and correction data have been described elsewhere⁽¹⁰⁾.

For the measurements on hashium-vanadium and hashiumchromium alloys, samples having black-body holes 0.4 to 0.6 mm in diameter and 3 mm deep were employed. Independent experiments conducted with graphite as a comparison standard ascertained emissivity coefficients of better than 0.995 for this hole geometry, thus leaving only a small temperature correction due to non-black body conditions⁽¹⁰⁾.

After loading the specimen into the furnace, the chamber was repeatedly evacuated and refilled with high purity helium and finally pressurized to 1.1 atmospheres. Residual gaseous impurities contained in the helium were gettered by a strip of titanium foil heated resistively inside the furnace. The specimens were then rapidly heated to within approximately 50°C of the suspected melting temperatures, and then the temperature gradually raised until melting was detected. The temperatures were measured with a disappearingfilament type pyrometer, sighting through a quartz port in the furnace wall. To enhance the sensitivity in detecting incipient melting, a photoelectric transducer system⁽¹¹⁾ was employed for very heterogeneously melting alloys.

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The differential-thermoanalytical studies were carried out using an apparatus which has been described in an earlier publication⁽¹²⁾. The runs were made under vacuum as well as under high purity helium (1.1 atm). Annealed tantalum served as comparison standard and tantalum-clad graphite as crucible material. Because the maximum temperatures reached in the experiments were as a rule less than 1600°C, no adverse interaction effects were noticeable.

C. METALLOGRAPHIC, X-RAY, AND CHEMICAL ANALYSIS

For the microscopic examinations, the specimens were mounted in a mixture of diallylphtalate and lucite-coated copper powder and preground on silicon-carbide papers in the order of decreasing degrees of coarseness. They were polished on microcloth, using a slurry of Linde "B" alumina (0.05μ) in 5% chromic acid solution. The hafnium-chromium alloys were electroetched in a 0.5% aqueous oxalic acid solution. Hafnium-vanadium alloys containing up to 40 At% vanadium were first electroetched in 0.5% oxalic acid solution, and subsequently treated with a 25% acid solution (6 parts HNO₃, 2 parts HCl, and 2 parts HF) to remove the stain from the anodizing treatment.

Approximately one-fourth of the processed samples were analyzed for oxygen and nitrogen, using a gas-fusion analyzer. No increase of these impurities in respect to the contaminant levels of starting materials were detected. Although no metal analyses were performed, weighing of the samples before and after each processing step indicated only negligible changes in respect to the weighed-in compositions.

Since the structures of the phases occurring in both systems were known from previous work, only powder diffraction patterns, using

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 $Cu-K_a$ as well as $Cr-K_a$ radiation, were prepared from all experimental alloys and the film strips evaluated.

III. RESULTS

A. THE HAFNIUM-VANADIUM SYSTEM

The melting point data in Figure 1 clearly indicate the formation of two eutectic equilibria on both sides of the congruently melting, intermediate phase HfV_2 ; this result was independently verified by metallographic analysis.





(Temperature Error Figures Based on Reproducibility)

DTA-thermograms taken on hafnium-rich alloys indicate a lowering of the $a-\beta$ hafnium transition temperature by vanadium (Figure 2); in addition to the bivariant transformation reaction at approximately 1600°C, a second, sharper thermal arrest in the vicinity of 1200°C represents the eutectoid decomposition of the β -phase; this sequence of reactions becomes more evident from the series of DTA-thermograms obtained on alloys with gradually increased vanadium contents (Figure 3). The considerable lag of the eutectoid reaction in the hypoeutectoid alloys upon cooling probably is attributable to hindered HfV₂-nucleation within β -hafnium. In agreement with this supposition also is the observation that this temperature lag was absent in hypereutectoid alloys, which contained excess HfV₂ in the form of intragranular precipitates in the β -phase.

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Figure 2. DTA-Thermogram of a Hafnium-Vanadium (95-5 At%) Alloy.



Figure 3. DTA-Thermograms (Cooling) of Hafnium-Rich Hf-V Alloys.

Alloys containing between 2 and 19 At% vanadium and which were equilibrated above 1200°C, contained corresponding amounts of proeutectoid a-hafnium in a eutectoid matrix [Figure 4(a) and 4(b)]. Another alloy Hf-V (81-19 At%) was purely eutectoid (Figure 5), whereas the sample containing 22 At% V is unmistakingly hypereutectoid (Figure 6). Based upon the metallographic observations, as well as the DTA-results, the composition of the eutectoid was placed at 19 At% V and a temperature of $1190 \pm 20^{\circ}$ C. Although an average of the DTA results (Figure 2) would indicate a 10 to 20°C higher temperature than that which was finally adopted, the lower temperature was chosen, since precipitation of HfV₂ from β -hafnium tended to supplant the eutectoid reaction and thus the isothermal reaction temperature measured in hypereutectoid alloys was too high.



Figures 4(a) and 4(b): Proeutectoid a-Hf (Stained Dark by Electroetch) and Eutectoid (Light).

Figure 4(a): Hf-V (95-5 At%), Cooled at 12°C per Second X325 from 1650°C.



Figure 4(b): Hf-V (85-15 At%), Cooled at 30°C per Second X325 from 1600°C.



Figure 5. Hf-V (81-19 At%), Cooled at 3°C per Second from 1400°C.

X2500

a-Hf + HfV₂ Eutectoid. (Structure not Completely Resolved)



Figure 6: Hf-V (78-22 At%), Cooled at 3°C per Second from 1400°C.

X760

HfV₂ Precipitates in a Eutectoid Matrix.

The eutectoid reaction appears to be fast and the β -phase could not be retained even after tin-quenching of the alloys from above peritectoid temperatures. A maximum solid solubility 23.5 At% vanadium in β -hafnium was deduced mainly from a microscopic examination of alloys after equilibration and quenching from the β -Hf + HfV, eutectic temperature.

Melted alloys from the concentration range 25 to 42 At% vanadium showed primary crystallized β -Hf in a eutectic matrix (Figure 7). The alloy with 43 At% V was purely eutectic (Figure 8), whereas alloys in the range from 44 to 63 At% V contained primary crystallized HfV₂ and eutectic. Two samples located at 66 and 66.6 At% V were single phase HfV₂ after quenching from the melt; however, the alloy containing 68 At% V already showed approximately 40% eutectic besides primary crystallized HfV, (Figure 9).



Figure 7: Hf-V (73-27 At%), Cooled at ~60°C per Second X840 from 1600°C.

Primary β -Hf (Decomposed, Dark Grains) in a Matrix of β -Hf + HfV_2 Eutectic.



Figure 8. Hf-V (57-43 At%), Cooled at 20°C per Second from 1460°C.

 β -Hf + HfV₂ Eutectic

X1000



Figure 9: Hf-V (32-68 At%), Rapidly Cooled from 1540°C X600

The solubility of hafnium in vanadium was not specifically investigated, although microscopic examination of a melted alloy containing 95 At% V showed the alloy to be close to the phase boundary at 1500°C. Lattice parameter measurements on alloys quenched from 1500°C yielded an average expansion of the vanadium lattice from a = 3.206 Å, for pure vanadium, to a = 3.046 Å for the hafnium-saturated solid solution. In the 1200°C-equilibrated alloys, the parameter of the hafnium saturated solution was a = 3.031 Å. Taking into account the atomic radii of the alloy partners, these parameters would suggest a maximum hafnium solubility of ~4 At% at 1500°C, and of ~1 At% at 1200°C.

No additional phases were detected in the lower temperature $(<1200\,^{\circ}C)$ heat-treatments, and the only modification observed for the HfV_2 -phase was the C15-type. On the average and independent of the composition, a parameter of a = 7.388 Å was measured in the alloy series heat treated at $1100\,^{\circ}C$. Towards higher temperatures, the phase seems to exhibit a small homogeneity range as evidenced by the change of the lattice parameter from

a = 7.398 Å, obtained in hafnium-rich alloys, to a = 7.386 Å in excess-vanadium alloys. The experimental data have been combined to yield the phase diagram of the system depicted in Figure 10.





B. THE HAFNIUM-CHROMIUM SYSTEM

The constitution diagram of the hafnium-chromium system is very similar to that of hafnium-vanadium. Because the experimental techniques were the same as applied for the hafnium-vanadium system, only a brief description of the experimental results will be given.

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The measured solidus temperatures and solid state reaction isotherms are recorded in Figure 11. Representative DTA-thermograms of hafnium-rich alloys are shown in Figures 12 and 13, and micrographs in Figures 14 through 19. A proposed phase diagram for the hafnium-chromium system is depicted in Figure 20.





(Temperature Error Figures Based on Reproducibility)



Figure 12. DTA-Thermogram of a Hafnium-Chromium Alloy Containing 4 At% Cr.



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Figure 13. DTA-Thermograms (Cooling) of Hafnium-Rich Hf-Cr Alloys.

(Temperature Figures Shown on Curves are Pyrometric Control Measurements)



Figure 14(a): X720 Hf-Cr (96-4 At%), Cooled at 4°C per Second from 1700°C.

Proeutectoid a Hf (brightgrains) and Small Amounts of Eutectoid.



Figure 14(b). X375 Hf-Cr (90-10 At%), Cooled at 3°C per Second from 1550°C.

Slightly Hypo-Eutectoid Composition.

Eutectoid Not Resolved.



Figure 14 (c). X1000 Hf-Cr (88.5-11.5 At%), Cooled at 9°C per Second from 1400°C.

a-Hf + HfCr₂ Eutectoid, Lamellar Structure not Resolved.

Figures 14(a) through 14(c): Micrographs of Hafnium-Rich Hf-Cr Alloys.



Figure 15. Hf-Cr (63-37 At%), Rapidly Cooled from 1530°C. X1000 Primary β -Hf in a Matrix of β -Hf + HfCr₂ Eutectic.



Figure 16. Hf-Cr (59-41 At%), Rapidly Cooled from 1510°C. X1000 β -Hf + HfCr₂ Eutectic



Figure 17. Hf-Cr (50-50 At%), Rapidly Cooled from 1650°C. X1000 Primary HfCr, in a Eutectic Matrix.



Figure 18. Hf-Cr (13-87 At%), Rapidly Cooled from 1700°C. X1000 Isolated Grains of Primary Chromium in a Predominantly Eutectic Structure.



Figure 19. Hf-Cr (10-90 At%), Cooled at 30°C per Second X760 from 1730°C. Primary Chromium and HfCr, + Cr Eutectic.

The eutectoid reaction in this system also occurs with high speed and the β -hafnium phase could not be retained by tin-quenching the alloys from temperatures above 1360°C. X-ray patterns of alloys from the concentration region Hf + HfCr₂, regardless of the heat treatment, therefore always showed the pattern of a-Hf beside the equivalent amount of HfCr₂.

Melted and quenched alloys, as well as samples annealed at subsolidus temperature, invariably showed the presence of only the hexagonal, Cl4-type modification of HfCr₂; no signs of a transition could be detected in the DTA-runs. At high temperatures (~1500°C), the phase was found to exhibit a noticeable range of homogeneity, extending from approximately 64 At% Cr (a = 5.090 Å; c = 8.25 Å), to 67 At% Cr (a = 5.056 Å; c = 8.21 Å), as verified independently by metallographic inspection of the alloys. In disagreement with the earlier findings by Elliott⁽⁶⁾ and by Alisova et al. ⁽⁸⁾, we were unable to detect the cubic, Cl5-type, modification in any of the heat-treated







alloys, which included a sample series which was heat treated for 220 hrs at 900°C. Alisova et al. $^{(8)}$ state in their paper, however, that the transformation occurs rather sluggishly; one therefore may argue that equilibrium was not attained in our experiments. Nevertheless, regardless of whether or not a transition of the HfCr₂-phase does occur at some lower temperature, our experiments do ascertain that the hexagonal is the stable form above 1100°C.

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